INTEGRATED CIRCUITS

DATA SHEET



74F779

8-bit bidirectional binary counter (3-State)

Product specification

1989 Sep 20

IC15 Data Handbook





8-bit bidirectional binary counter (3-State)

74F779

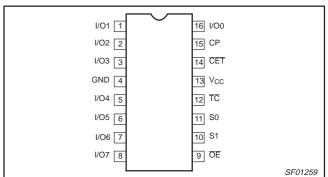
FEATURES

- Multiplexed 3-State I/O ports for bus oriented applications
- Built-in look-ahead carry capability
- Center power pins to reduce effects of package inductance
- Count frequency 145MHz typical
- Supply current 90mA typical
- See 74F269 for 24-pin separate I/O port version
- See 74F579 for 20-pin version
- See 74F1779 for extended function version of the 74F799

DESCRIPTION

The 74F779 is a fully synchronous 8-stage Up/Down Counter with multiplexed 3-State I/O ports for bus-oriented applications. All control functions (hold, count up, count down, synchronous load) are controlled by two mode pine (S0, S1). The device also features carry look-ahead for easy cascading. All state changes are initiated by the rising edge of the clock. When $\overline{\text{CET}}$ is High the data outputs are held in their current state and $\overline{\text{TC}}$ is held High. The $\overline{\text{TC}}$ output is not recommended for use as a clock or asynchronous reset due to the possibility of decoding spikes.

PIN CONFIGURATION



TYPE	TYPICAL f _{MAX}	TYPICAL SUPPLY CURRENT (TOTAL)
74F779	145MHz	90mA

ORDERING INFORMATION

DESCRIPTION		PKG DWG #		
16-Pin Plastic DIP	N74F779N	SOT38-4		
16-Pin Plastic SOL	N74F779D	SOT 162-1		

INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

PINS	DESCRIPTION	74F(U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
I/On	Data inputs	3.5/1.0	70μA/0.6mA
1/011	Data outputs	150/40	3.0mA/24mA
S0, S1	Select inputs	1.0/1.0	20μA/0.6mA
ŌĒ	Output Enable input (active Low)	1.0/1.0	20μA/0.6mA
CET	Count Enable Trickle input (active Low)	1.0/1.0	20μA/0.6mA
СР	Clock input (active rising edge)	1.0/1.0	20μA/0.6mA
TC	Terminal Count output (active Low)	50/33	1.0mA/20mA

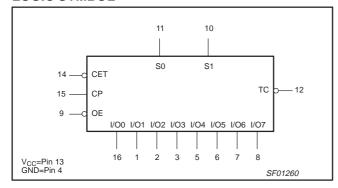
NOTE:

One (1.0) FAST Unit Load is defined as: $20\mu A$ in the High state and 0.6mA in the Low state.

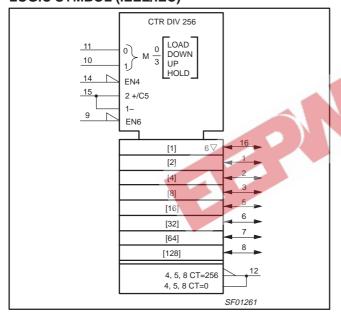
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LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

		INPUTS	3		OPERATING MODE
S1	S0	CET	ΟE	СР	
Х	Х	Х	Н	Χ	I/O0 to I/O7 in High impedance
Х	X X X L X		Х	Flip-flop outputs appear on I/O lines	
L	L	Х	Н	1	Parallel load all flip-flops
(not	LL)	Н	Х	1	Hold (TC held High)
Н	L	L	Χ	1	Count up
L	Н	L	Χ	1	Count down

H = High voltage level L = Low voltage level

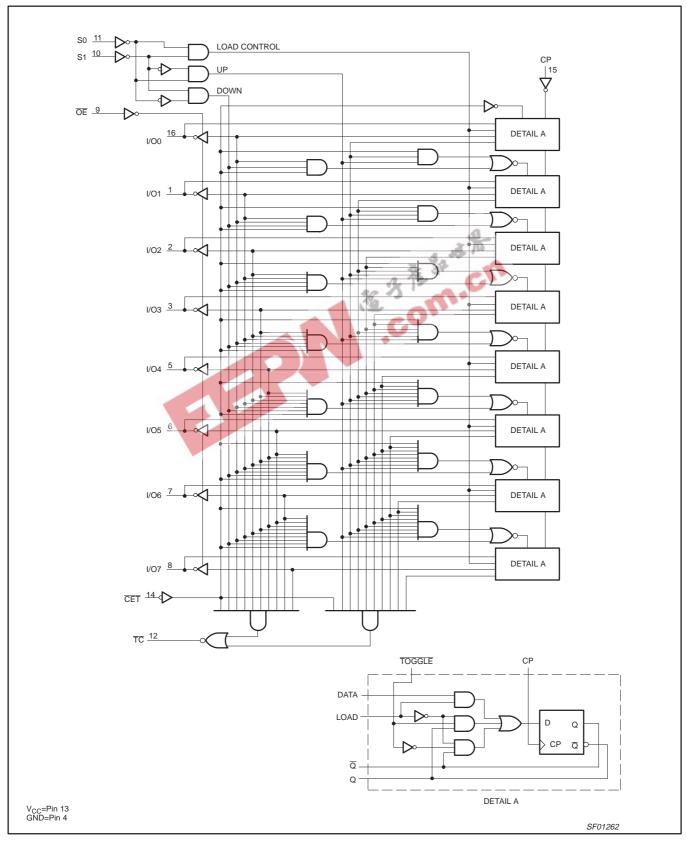
L = Low voltage level
X = Don't care
↑ = Low-to-High clock transition
(not LL) = S0 and S1 should never be Low voltage level at the same time in the hold mode only.

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LOGIC DIAGRAM



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ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limits set forth in this table may impair the useful life of the device. Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER		RATING	UNIT
V _{CC}	Supply voltage		-0.5 to +7.0	V
V _{IN}	Input voltage		-0.5 to +7.0	V
I _{IN}	Input current	-30 to +5	mA	
V _{OUT}	Voltage applied to output in High output state	–0.5 to V _{CC}	V	
	Comment and like the substitute I am automate the	TC	40	mA
lout	Current applied to output in Low output state	I/On	48	mA
T _{amb}	Operating free-air temperature range	•	0 to +70	°C
T _{stg}	Storage temperature	-65 to +150	°C	

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	25-	LIMITS				
STWIBUL	PARAMETER		43	MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage		3	4.5	5.0	5.5	V
V _{IH}	High-level input voltage		CO	2.0			V
V _{IL}	Low-level input voltage					0.8	V
I _{IK}	Input clamp current)				-18	mA
	High level output gurrent	TC				-1	mA
ЮН	High-level output current	I/On				-3	mA
	I am land a day a survey	TC				20	mA
l _{OL}	Low-level output current	I/On				24	mA
T _{amb}	Operating free-air temperature range	-		0		70	°C

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DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

						LIMITS			
SYMBOL	PARAMETER		TEST	TEST CONDITIONS ^{NO TAG}				MAX	UNIT
		тс	V _{CC} = MIN, V _{IL} = MAX	4	±10%V _{CC}	2.5			V
V			V _{IL} = MIN	$I_{OH} = -1 \text{mA}$	±5%V _{CC}	2.7	3.4		V
V _{OH}	High-level output voltage	1/0-	$V_{CC} = MIN,$ $V_{IL} = MAX$)	±10%V _{CC}	2.4			V
		I/On	V _{IH} = MIN	$I_{OH} = -3mA$	±5%V _{CC}	2.7	3.3		V
.,	Column Low-level output voltage		$V_{CC} = MIN,$	I MAN	±10%V _{CC}		0.30	0.50	V
VOL			$V_{IL} = MAX$ $V_{IH} = MIN$	$I_{OL} = MAX$	±5%V _{CC}		0.35	0.50	V
V _{IK}	Input clamp voltage		V _{CC} = MIN, I _I	$V_{CC} = MIN, I_I = I_{IK}$			-0.73	-1.2	V
l.	Input current at maximum	I/On	$V_{CC} = 5.5V, V_I = 5.5V$ $V_{CC} = 5.5V, V_I = 7.0V$					1	mA
łı	input voltage	others	V _{CC} = 5.5V, \			100	μΑ		
I _{IH}	High-level input current	except	$V_{CC} = MAX,$	V _I = 2.7V	14	3/1		20	μΑ
I _{IL}	Low-level input current	I/On	$V_{CC} = MAX,$	$V_{I} = 0.5V$	1000			-0.6	mA
I _{IH} +I _{OZH}	Off-state output current High-level voltage applied	I/On	V _{CC} = MAX,	V _O = 2.7V	20.			70	μΑ
I _{IL} +I _{OZL}	Off-state output current Low-level voltage applied	I/On	V _{CC} = MAX,	$V_{CC} = MAX, V_O = 0.5V$				-600	μΑ
I _{OS}	Short-circuit output current ^N	O TAG	$V_{CC} = MAX$	V _{CC} = MAX				-150	mA
		Іссн					82	116	mA
I _{CC}	Supply current (total)	ICCL	V _{CC} = MAX				91	128	mA
		¹ ccz]				97	136	mA

1. For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.

AC ELECTRICAL CHARACTERISTICS

					LIMIT	'S		
SYMBOL	PARAMETER	TEST CONDITIONS	l '	_{lmb} = +25° V _{CC} = +5V 50pF, R _L =	/	T _{amb} = 0°0 V _{CC} = +5 C _L = 50pF,	UNIT	
			MIN	TYP	MAX	MIN	MAX	
f _{MAX}	Maximum clock frequency	Waveform 1	125	145		115		MHz
t _{PLH}	Propagation delay	Waveform 1	4.5	7.0	10.5	4.5	11.0	ns
t _{PHL}	CP to I/On		5.5	8.0	10.5	5.5	11.0	ns
t _{PLH}	Propagation delay	Waveform 1	4.5	7.0	9.0	4.5	10.0	ns
t _{PHL}	CP to TC		4.5	7.0	9.0	4.5	10.0	ns
t _{PLH}	Propagation delay	Waveform 2	3.0	4.5	6.5	2.5	7.5	ns
t _{PHL}	CET to TC		3.0	5.5	7.5	2.5	8.0	ns
t _{PZH}	Output Enable time to	Waveform 4	2.5	4.5	7.0	2.5	8.0	ns
t _{PZL}	High or Low level	Waveform 5	4.5	6.5	9.0	4.5	9.5	ns
t _{PHZ}	Output Enable time from	Waveform 4	1.0	3.0	6.5	1.0	8.0	ns
t _{PLZ}	High or Low level	Waveform 5	1.0	4.0	7.0	1.0	8.0	ns

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All typical values are at V_{CC} = 5V, T_{amb} = 25°C.
 Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

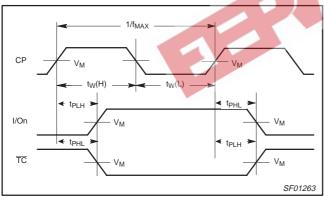
AC SETUP REQUIREMENTS

				LIMITS						
SYMBOL	PARAMETER	TEST CONDITIONS	T ₂	_{lmb} = +25° V _{CC} = +5V 50pF, R _L =	C , 500Ω	T _{amb} = 0°0 V _{CC} = +5 C _L = 50pF,	UNIT			
			MIN	TYP	MAX	MIN	MAX			
$t_{s}(H)$ $t_{s}(L)$	Setup time, High or Low I/O _n to CP	Waveform 3	5.0 5.0			5.0 5.0		ns ns		
t _h (H) t _h (L)	Hold time, High or Low I/O _n to CP	Waveform 3	1.0 1.0			1.0 1.0		ns ns		
$t_{s}(H)$ $t_{s}(L)$	Setup time, High or Low CET to CP	Waveform 3	5.0 5.5			5.0 6.0		ns ns		
t _h (H) t _h (L)	Hold time, High or Low CET to CP	Waveform 3	0 0			0		ns ns		
t _S (H) t _S (L)	Setup time, High or Low Sn to CP	Waveform 3	8.0 8.0		4	8.5 8.5		ns ns		
t _h (H) t _h (L)	Hold time, High or Low Sn to CP	Waveform 3	0 0	- 4a	通用	0 0		ns ns		
t _w (H) t _w (L)	CP Pulse width, High or Low	Waveform 1	4.0 4.0	13	C	4.0 4.0		ns ns		

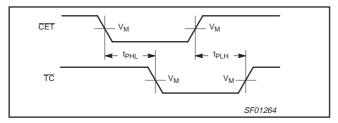
AC WAVEFORMS

For all waveforms, $V_M = 1.5V$.

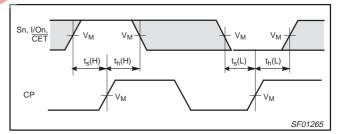
The shaded areas indicate when the input is permitted to change for predictable output performance.



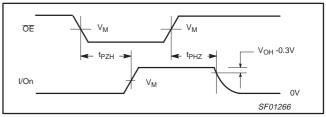
Waveform 1. Propagation Delay, Clock Input to Output, Clock Pulse Width, and Maximum Clock Frequency



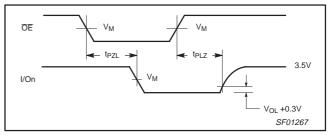
Waveform 2. Propagation Delay $\overline{\text{CET}}$ Input to Terminal Count Output



Waveform 3. Data Setup and Hold Times



Waveform 4. 3-State Output Enable Time to High Level and Output Disable Time from High Level

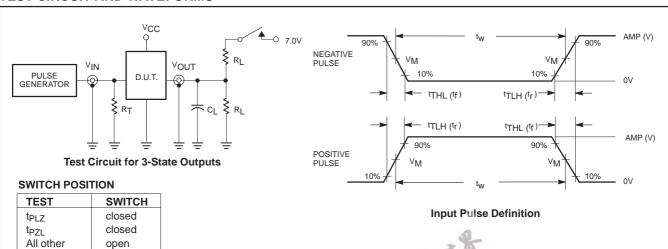


Waveform 5. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

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TEST CIRCUIT AND WAVEFORMS



DEFINITIONS:

R_L = Load resistor;

see AC electrical characteristics for value.
Load capacitance includes jig and probe capacitance; see AC electrical characteristics for value.

Termination resistance should be equal to Z_{OUT} of pulse generators.

-	30	INP	INPUT PULSE REQUIREMENTS									
	amily	amplitude	VM	rep. rate	t _w	t _{TLH}	t _{THL}					
l	7 4F	3.0V	1.5V	1MHz	500ns	2.5ns	2.5ns					

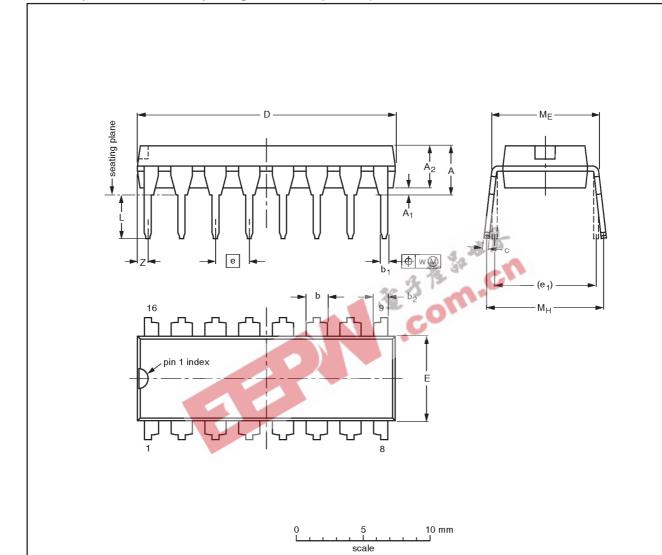
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DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	b ₂	С	D ⁽¹⁾	E ⁽¹⁾	е	e ₁	L	ME	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

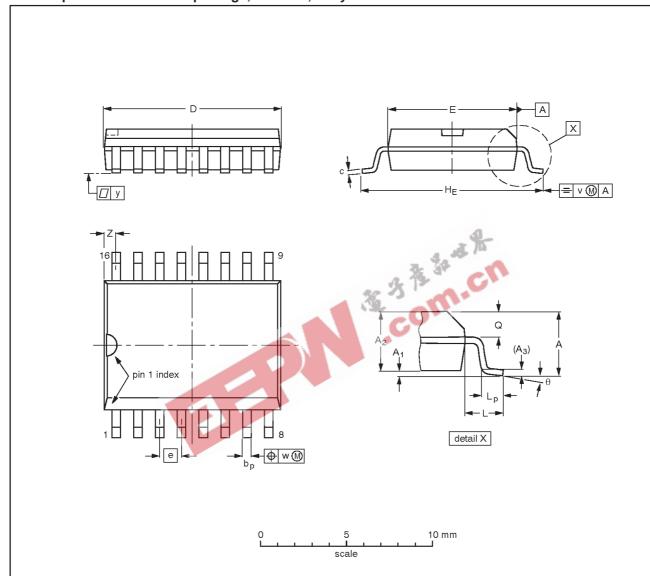
OUTLINE VERSION		REFER	EUROPEAN	ISSUE DATE		
	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT38-4						92-11-17 95-01-14

8-bit bidirectional binary counter (3-State)

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SO16: plastic small outline package; 16 leads; body width 7.5 mm

SOT162-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	10.5 10.1	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.41 0.40	0.30 0.29	0.050	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE	
SOT162-1	075E03	MS-013AA				95 01 24 97-05-22	

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NOTES



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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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^[1] Please consult the most recently issued datasheet before initiating or completing a design.

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